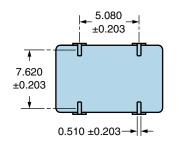


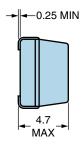
| ELECTRICAL SPECIFICATIONS             |   |  |
|---------------------------------------|---|--|
| Nominal Frequency                     | 18.000MHz   |  |
| Frequency Tolerance/Stability         | ±100ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration) |  |
| Aging at 25°C                         | ±5ppm/year Maximum  |  |
| Operating Temperature Range           | -20°C to +70°C  |  |
| Supply Voltage                        | 5.0Vdc ±10%   |  |
| Input Current                         | 45mA Maximum (Unloaded)   |  |
| Output Voltage Logic High (Voh)       | Vdd-0.4Vdc Minimum (IOH = -16mA)  |  |
| Output Voltage Logic Low (Vol)        | 0.4Vdc Maximum (IOL = +16mA)  |  |
| Rise/Fall Time                        | 4nSec Maximum (Measured at 20% to 80% of waveform)  |  |
| Duty Cycle                            | 50 ±10(%) (Measured at 1.4Vdc with TTL Load; Measured at 50% of waveform with HCMOS Load)   |  |
| Load Drive Capability                 | 50pF HCMOS Load Maximum   |  |
| Output Logic Type                     | CMOS  |  |
| Pin 1 Connection                      | Tri-State (Disabled Output: High Impedance)   |  |
| Tri-State Input Voltage (Vih and Vil) | +2.0Vdc Minimum to enable output, +0.8Vdc Max, to disable output, No Connect to enable output.  |  |
| Standby Current                       | 50μA Maximum (Pin 1 = Ground)   |  |
| Disable Current                       | 30mA Maximum (Pin 1 = Ground)   |  |
| Absolute Clock Jitter                 | ±250pSec Maximum, ±100pSec Typical  |  |
| One Sigma Clock Period Jitter         | ±50pSec Maximum   |  |
| Start Up Time                         | 10mSec Maximum  |  |
| Storage Temperature Range             | -55°C to +125°C   |  |

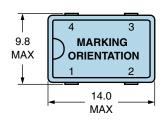
| ENVIRONMENTAL & MECHANICAL SPECIFICATIONS |                                       |  |
|---|---------------------------------------|--|
| Fine Leak Test                            | MIL-STD-883, Method 1014, Condition A |  |
| Gross Leak Test                           | MIL-STD-883, Method 1014, Condition C |  |
| Mechanical Shock                          | MIL-STD-202, Method 213, Condition C  |  |
| Resistance to Soldering Heat              | MIL-STD-202, Method 210               |  |
| Resistance to Solvents                    | MIL-STD-202, Method 215               |  |
| Solderability                             | MIL-STD-883, Method 2003              |  |
| Temperature Cycling                       | MIL-STD-883, Method 1010              |  |
| Vibration                                 | MIL-STD-883, Method 2007, Condition A |  |



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**





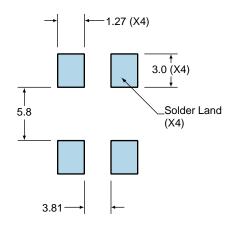


| PIN | CONNECTION                    |
|-----|-------------------------------|
| 1   | Tri-State (High<br>Impedance) |
| 2   | Ground                        |
| 3   | Output                        |
| 4   | Supply Voltage                |

| LINE | MARKING   |
|------|---|
| 1    | ECLIPTEK  |
| 2    | 18.000M   |
| 3    | PXXYZZ P=Configuration Designatol XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year |

#### **Suggested Solder Pad Layout**

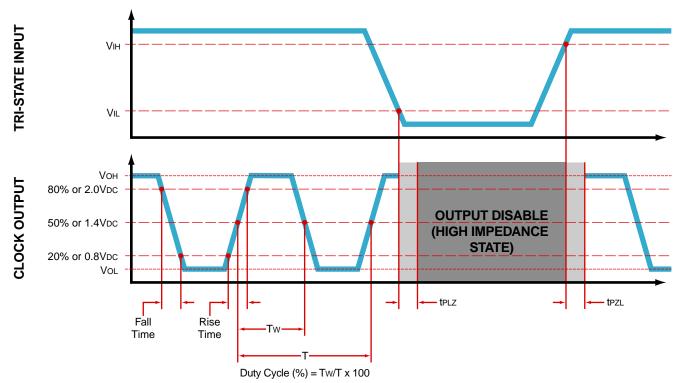
All Dimensions in Millimeters



All Tolerances are ±0.1



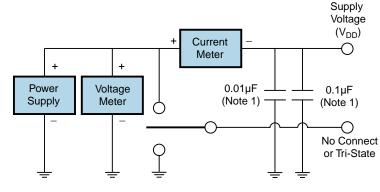
#### **OUTPUT WAVEFORM & TIMING DIAGRAM**

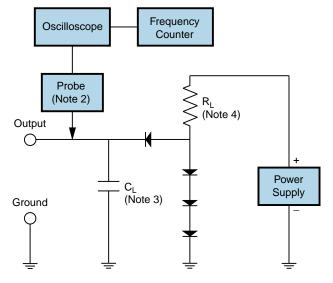


#### **Test Circuit for TTL Output**

| Output Load<br>Drive Capability | R <sub>L</sub> Value<br>(Ohms) | C <sub>L</sub> Value<br>(pF) |
|---------------------------------|--------------------------------|------------------------------|
| 10TTL                           | 390                            | 15                           |
| 5TTL                            | 780                            | 15                           |
| 2TTL                            | 1100                           | 6                            |
| 10LSTTL                         | 2000                           | 15                           |
| 1TTL                            | 2200                           | 3                            |

Table 1:  $R_L$  Resistance Value and  $C_L$  Capacitance Value Vs. Output Load Drive Capability





Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

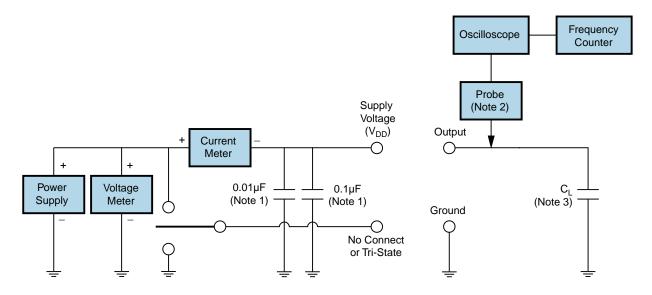
Note 3: Capacitance value  $C_{\mathsf{L}}$  includes sum of all probe and fixture capacitance.

Note 4: Resistance value R<sub>L</sub> is shown in Table 1. See applicable specification sheet for 'Load Drive Capability'.

Note 5: All diodes are MMBD7000, MMBD914, or equivalent.



### **Test Circuit for CMOS Output**



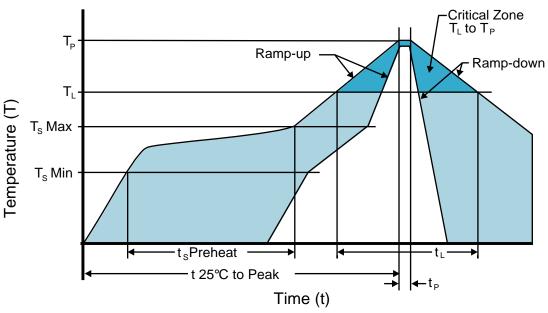
Note 1: An external  $0.1\mu\text{F}$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu\text{F}$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



### **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

| T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate) | 5°C/second Maximum                                     |
|---|--|
| Preheat   |  |
| - Temperature Minimum (T <sub>s</sub> MIN)          | N/A  |
| - Temperature Typical (T <sub>S</sub> TYP)          | 150°C  |
| - Temperature Maximum (T <sub>s</sub> MAX)          | N/A  |
| - Time (t <sub>s</sub> MIN)                         | 60 - 120 Seconds                                       |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 5°C/second Maximum                                     |
| Time Maintained Above:                              |  |
| - Temperature (T∟)                                  | 150°C  |
| - Time (t∟)   | 200 Seconds Maximum                                    |
| Peak Temperature (T <sub>P</sub> )                  | 240°C Maximum  |
| Target Peak Temperature (T <sub>P</sub> Target)     | 240°C Maximum 1 Time / 230°C Maximum 2 Times           |
| Time within 5°C of actual peak (tp)                 | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate                                      | 5°C/second Maximum                                     |
| Time 25°C to Peak Temperature (t)                   | N/A  |
| Moisture Sensitivity Level                          | Level 1  |

### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.